

Features

Pb-Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	60	Vdc
Drain-Gate Voltage (RGS=1.0MΩ)	V_{DGR}	60	Vdc
Drain Current	I_D	±115	mAdc
-Continuous TC=25 (Note 1)	I_D	±75	
TC=100 (Note 1)	I_{DM}	±800	
-Pulsed (Note 2)			
Gate-Source Voltage	V_{GS}	±20	Vdc
-Continuous	V_{GSM}	±40	Vpk
-Non-repetitive (tp ≤50μs)			

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 3) TA=25 Derate above 25	P_D	225 1.8	mW mW/
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	/W
Total Device Dissipation Alumina Substrate, (Note 4) TA=25 Derate above 25	P_D	300 2.4	mW mW/
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	/W
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	

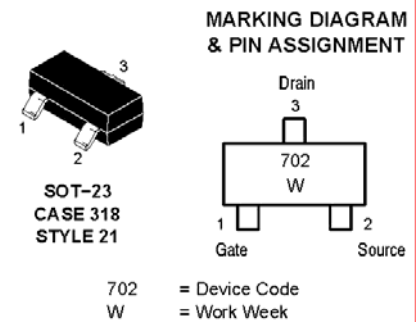
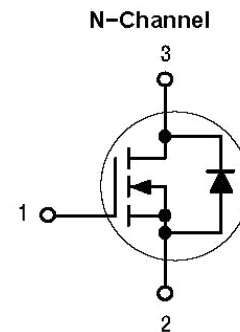
1. The Power Dissipation of the package may result in a lower continuous drain current.

2. Pulse Test: Pulse Width≤300μs, Duty Cycle≤2.0%.

3. FR-5 = 1.0 X 0.75 X 0.062 in.

4. Alumina =0.4 x 0.3 x 0.025 in 99.5% alumina.

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	$I_D MAX$
60V	7.5Ω@ 10V,500mA	115mA



ORDERING INFORMATION

Device	Package	Shipping†
2N7002LT1	SOT-23	3000 Tape & Reel
2N7002LT3		10,000 Tape&Reel
2N7002LT1G	SOT-23 (Pb-free)	3000 Tape & Reel
2N7002LT3G		10,000 Tape&Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and Reel Packaging Specifications Brochure, BRD8011/D

ELECTRICAL CHARACTERISTICS ($T_A=25$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Drain-Source Breakdown Voltage ($V_{GS}=0, I_D=10\mu A$)	$V_{(BR)DSS}$	60	-	-	Vdc
Zero Gate Voltage Drain Current ($V_{GS}=0, V_{DS}=60V$)	I_{DSS}	-	-	1.0 500	μA
Gate-Body Leakage Current, Forward ($V_{GS}=20V$)	I_{GSSF}	-	-	100	nA
Gate-Body Leakage Current, Forward ($V_{GS}=-20V$)	I_{GSSR}	-	-	-100	nA
ON CHARACTERISTICS (Note 5)					
Gate Threshold Voltage ($V_{DS}=V_{GS}, I_D=250\mu A$)	$V_{GS(th)}$	1.0	-	2.5	Vdc
On-State Drain Current ($V_{DS}\geq 2.0V_{DS(on)}, V_{GS}=10V$)	$I_{D(on)}$	500	-	-	mA
Static Drain-Source On-State Voltage ($V_{DS}=V_{GS}, I_D=500\mu A$) ($V_{GS}=V_{GS}, I_D=50\mu A$)	$V_{DS(on)}$	- -	- -	3.75 0.375	Vdc
Static Drain-Source On-State Resistance ($V_{GS}=10V, I_D=500mA$) ($V_{GS}=5.0V, I_D=50mA$)	$r_{DS(on)}$	- - - -	- - - -	7.5 13.5 7.5 13.5	Ohms
Forward Transconductance ($V_{DS}\geq 2.0V_{DS(on)}, I_D=200mA$)	g_{FS}	80	-	-	mmhos
DYNAMIC CHARACTERISTICS					
Input Capacitance ($V_{DS}=25V, V_{GS}=0, f=1.0MHz$)	C_{iss}	-	-	50	pF
Output Capacitance ($V_{DS}=25V, V_{GS}=0, f=1.0MHz$)	C_{oss}	-	-	25	pF
Reverse Transfer Capacitance ($V_{DS}=25V, V_{GS}=0, f=1.0MHz$)	C_{rss}	-	-	5.0	pF
SWITCHING CHARACTERISTICS (Note 5)					
Turn-On Delay Time	($V_{DD}=25V, I_D\approx 500mA, R_G=25\Omega, R_L=50\Omega, V_{gen}=10V$) $t_{d(on)}$	-	-	20	ns
Turn-Off Delay Time	$t_{d(off)}$	-	-	40	ns
BODY-DRAIN DIODE RATINGS					
Diode Forward On-Voltage ($I_S=11.5mA, V_{GS}=0V$)	V_{SD}	-	-	-1.5	Vdc
Source Current Continuous (Body Diode)	I_S	-	-	-115	mA
Source Current Pulsed	I_{SM}	-	-	-800	mA

5. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2.0\%$.

TYPICAL ELECTRICAL CHARACTERISTICS

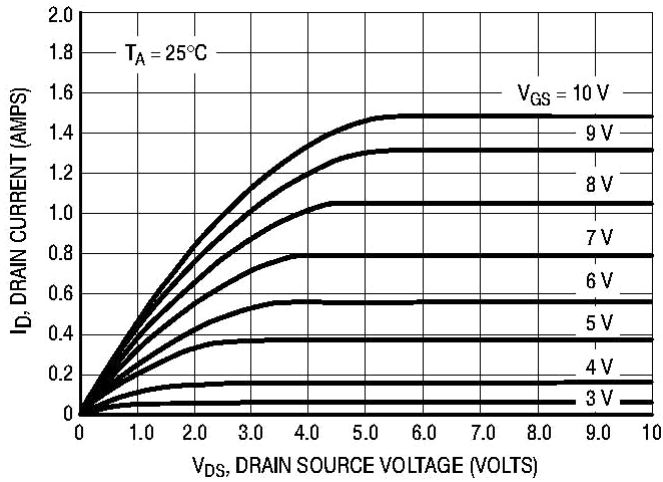


Figure 1. Ohmic Region

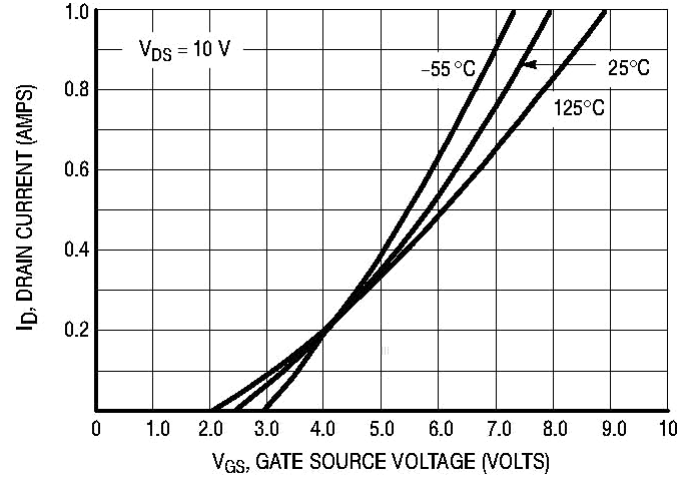


Figure 2. Transfer Characteristics

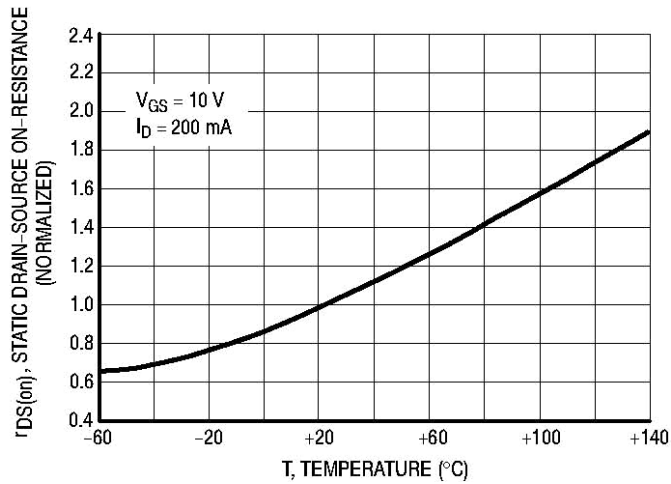


Figure 3. Temperature versus Static
Drain-Source On-Resistance

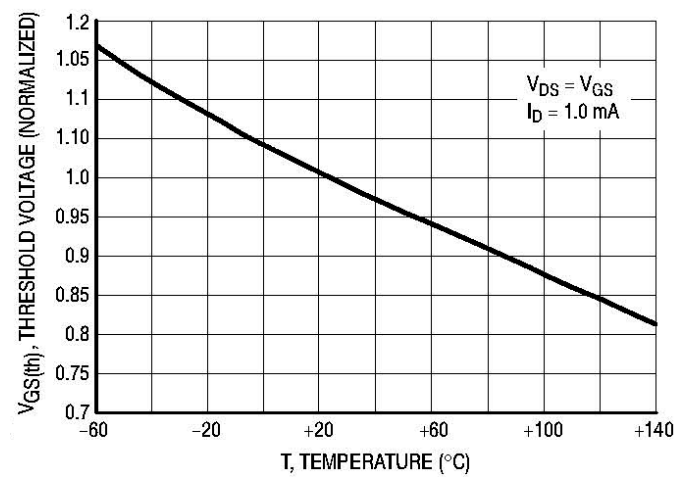


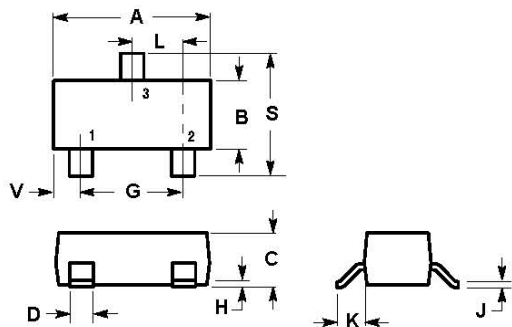
Figure 4. Temperature versus Gate
Threshold Voltage

PACKAGE DIMENSIONS

SOT-23 (TO-236)

CASE 318-08

ISSUE AH



NOTES:

- 1.DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982.
- 2.CONTROLLING DIMENSION:INCH.
- 3.MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS.MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL
- 4.318-03 AND -07 OBSOLETE, NEW STANDARD 318-08.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

STYLE21:

- PIN1. GATE**
2.SOURCE
3.DRAIN

SOLDERING FOOTPRINT*

